

OX-601 Oven Controlled Crystal Oscillator



Features

- 4-Pin SMD package
- Fast warm-up
- Frequency Range, 10 MHz to 40 MHz
- Standard freq: 10, 20, 38.4 MHz,
- High Relability (based on fully intergrated Design)
- Low Power

Applications

- Base stations
- Test equipment
- Small Cell
- Military communication equipment
- Stratum 3
- SyncE; 1588

	F	requency	Stabilities ¹	10 to 40 MH	7	
Parameter	Min	Typical	Max	Units	Condition	
vs. operating temperature range (referenced to +25°C)	-20 -10		+20 +10	ppb ppb	-40 to +85℃ -40 to +85℃	Options ⁵
slope	-2		+2	ppb/°C	@ Temp stab. +-10ppb	
Initial tolerance vs. supply voltage change vs. load change vs. aging / day vs. aging / year vs. aging / 10 years	-0.5 -20 -5 500 -3	±20 ±10 ±2	+0.5 +20 +5 +500 3	ppm ppb ppb ppb ppb ppm	at time of shipment, nominal EFC V _s ±5% static Load ±5% static after 30 days of operation after 30 days of operation after 30 days of operation	
Holdover drift			5	ppb	over 24 hours, constant temperature (<±1°C) ; after 30 days continous opperation	
Start up time			200	msec		
Warm-up time			3	minutes	to ±20ppb of final frequency (1 hour read @ +25℃	ling)
Loop bandwith for wander generation compliance	3			mHz	MTIE compliant with GR-1244 Fig 5-5 TDEV compliant with GR-1244 Fig 5-4 measurement setup: oscillator stabilized hours at Constant Temperature (±1°C, s air), data collected over 100,000 seconds second intervals (-3dB cutoff, 1st order h pass loop filter)	; l 24 till at 1
Adev		7E-11			tau= 1.0 sec	

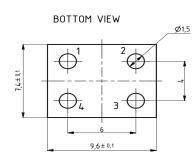
Performance Specifications

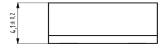
	Р	erforma	nce Spe	cification	IS	
		Suj	pply Voltag	e (Vs)		
Parameter	Min	Typical	Max	Units	Condition	
Supply voltage (standard)	3.135	3.3	3.465	VDC		
D		1.3	1.5	Watts	during warm-up	
Power consumption		0.4	0.5	Watts	steady state @ +25°C	
			RF Outpu	t		
Signal [standard]		HCI	MOS			
Load		15		pF		
Signal Level (Vol)			0.4	VDC	with Vs=3.3V and 15pF Lo	ad
Signal Level (Voh)	2.4			VDC	with Vs=3.3V and 15pF Lo	ad
Duty Cycle	45		55	%	@ (Voh-Vol)/2	
		Frequ	uency Tunir	ng (EFC)		
Tuning Range		Fixed OCX); No adjust			Opti- on ⁵
Tuning Range	±5		±12	ppm		g ø
Linearity			10%			
Tuning Slope		Pos	itive			
Control Voltage Range	0.0	1.4	2.8	V		
		Add	itional Para	meters		
Phase Noise ³		-99 -125 -145 -155 -160	-90 -120 -140 150 -155	dBc/Hz dBc/Hz dBc/Hz dBc/Hz dBc/Hz	10 Hz 100 Hz 1 kHz 10 kHz 100kHz	@ 20MHz
Weight			1.0	g		
Processing & Packing		Handling & Pr	rocessing No	te		
		Absolu	te Maximur	n Ratings		
Supply voltage (Vs)			3.8	V	with Vs=3.3 VDC	
Output Load			50	pF		
Operable Temperature Range	-40		+95	°C		
Storage Temperature Range	-40		+125	°C		

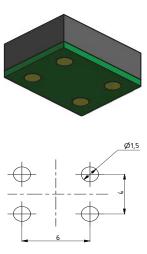
Outline Drawing / Enclosure

G349

Dimensions in mm







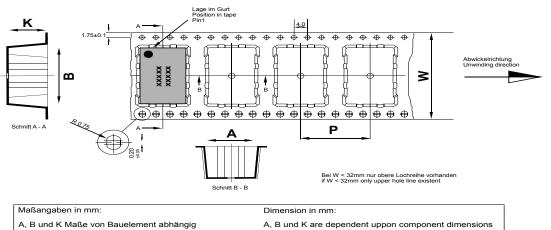
Recommended Pad Layout

OX-601				
Height "H"	cover material			
4.1	plastic			

Pin Connections				
1	I.C (Do not connect) / EFC (option)			
2	Ground (Case)			
3	RF Output			
4	Supply Voltage Input			

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Standard Shipping Method (OX-601)



A, B und K Maße von Bauelement abhängig Fertigungstoleranzen entsprechen der DIN IEC 286-3

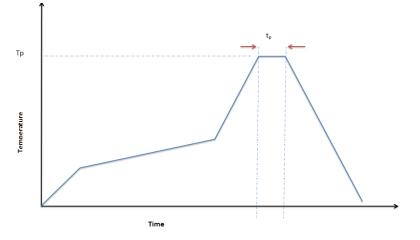
production tolerance complying DIN IEC 286-3 All dimensions in millimeters unless otherwise stated

Enclosure Type	Tape Width W (mm)	Quantity per meter	Quantity per reel	Dimension P
OX-601 (4.1 mm)	24	83.3	850	12

Reflow Profile

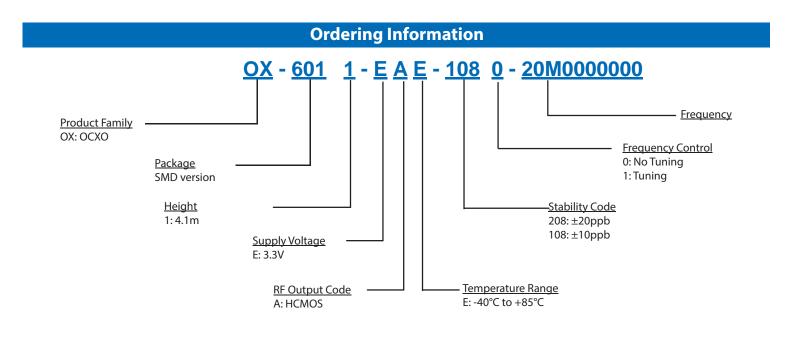
TP: max 250°C (@ solder joint, customer board level) Tp: max: 10...40 sec

Additional Information: This SMD oscillator has been designed for pick and place reflow soldering



Additional Environmental Conditions

Parameter	Description
Temperature Cycling	JESD22-A104-D Cond.G - 500cycles -40/+125C;cycle time 30min
Vibration, Sine	MIL-STD-883 Meth 2007 Cond A - 20g 20-2000Hz 4x in each 3 axis 4min sweep time
Mechanical Shock	MIL-STD-202 Meth 213B Cond. F - 1500g 0,5ms 6 shocks in each direction
Solderability	J-STD-002C Cond. A, Trough hole device; Cond.B, SMD (correspond to MIL-STD-883 Meth 2003) - 255C (diving Time 5 0,5sec.) Dip&Look with 8h damp pre-treatment: solder wetting >95%
Solvent resistance	MIL-STD-883 Meth 2003) - 255C (diving Time 5 0,5sec.) Dip&Look with
ESD	8h damp pre-treatment: solder wetting >95%
Moisture Sensit.	JESD22-A113-B - only if > MSL 1
RoHS compliance	100% RoHS 6 compliant
Washable	non-washable device
High temp operating life(HTOL)	MIL-STD-202 Meth108A Cond C - 1000h @ 105C power on
Low temp operating life(LTOL)	IEC 60068-2-1 Cond. Ae - 1000h @ -40C power on



Notes:

- 1. Contact factory for improved stabilities or additional product options. Not all options and codes are available at all frequencies.
- 2. Unless other stated all values are valid after warm-up time and refer to typical conditions for supply voltage, frequency control voltage, load, temperature (25°C).
- 3. Phase noise degrades with increasing output frequency.
- 4. Subject to technical modification.
- 5. Contact factory for availability.



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